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Title: “GaN Power ICs: Device Integration Delivers Application Performance”

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Biography:

Nick Fichtenbaum is a Co-Founder and VP of Engineering at Navitas Semiconductor and brings with him over 10 years of experience developing GaN materials and devices. Prior to Navitas, Nick was a VP at the private investment firm Malibu IQ, which led to the creation of Navitas. As an early employee of Transphorm, Nick served as both a member of the technical staff and Manager of Material Engineering, where he developed the GaN-on-Si epi technology. Nick has 40 peer-reviewed published articles based upon his GaN research, and been awarded 20 patents related to GaN power electronics. He holds a BA in Physics from Denison University, a BS in Electrical Engineering from Washington University in St. Louis, and a PhD in Electrical Engineering from the University of California, Santa Barbara, USA.

